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## **SiC JFET Division**

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## Silicon Carbide (SiC) Diode - EliteSiC, TO-247-2L, 50 A, 1200 V SiC Merged PiN-Schottky (MPS) Diode

Rev. C, Jan 2025

#### Description

UnitedSiC offers the 3<sup>rd</sup> generation of high performance SiC Merged-PiN-Schottky (MPS) diodes. With zero reverse recovery charge and 175°C maximum junction temperature, these diodes are ideally suited for high frequency and high efficiency power systems with minimum cooling requirements.

#### Features

- Maximum operating temperature of 175°C
- Easy paralleling
- Extremely fast switching not dependent on temperature
- No reverse or forward recovery
- Enhanced surge current capability, MPS structure
- 100% UIS tested
- AEC-Q101 qualified
- AECQ Qualified

Part Number	Package	Marking
UJ3D1250K2	TO-247-2L	UJ3D1250K2

DATASHEET

**J3D1250K2** 

CASE

2

1

CASE

1

2



- Power converters
- Industrial motor drives
- Switch mode power supplies
- Power factor correction modules





#### Maximum Ratings

Parameter	Symbol	<b>Test Conditions</b>	Value	Units	
DC blocking voltage	V <sub>R</sub>		1200	V	
Repetitive peak reverse voltage, T <sub>J</sub> =25°C	V <sub>RRM</sub>		1200	V	
Surge peak reverse voltage	V <sub>RSM</sub>		1200	V	
Maximum DC forward current	I <sub>F</sub>	T <sub>C</sub> = 112°C	50	А	
Non-repetitive forward surge current sine halfwave	I <sub>FSM</sub>	$T_{C}$ = 25°C, $t_{p}$ = 10ms	275	А	
Repetitive forward surge current	1	$T_{\rm C}$ = 25°C, $t_{\rm p}$ = 10ms	163.5		
sine halfwave, D=0.1	I <sub>FRM</sub>	T <sub>C</sub> = 110°C, t <sub>p</sub> = 10ms	99.6	A	
Non-monthly a nonlyform and a summary	1	T <sub>C</sub> = 25°C, t <sub>p</sub> = 10μs	2400		
Non-repetitive peak forward current	I <sub>F,max</sub>	$T_{C}$ = 110°C, $t_{p}$ = 10µs	2400	A	
i <sup>2</sup> t value	∫i <sup>2</sup> dt	$T_{c}$ = 25°C, $t_{p}$ = 10ms	378	A <sup>2</sup> s	
	D	T <sub>C</sub> = 25°C	319	W	
Power dissipation	P <sub>tot</sub> –	T <sub>C</sub> = 112°C	134		
Maximum junction temperature	T <sub>J,max</sub>		175	°C	
Operating and storage temperature	T <sub>J</sub> , T <sub>STG</sub>		-55 to 175	°C	
Soldering temperatures, wavesoldering only allowed at leads	T <sub>sold</sub>	1.6mm from case for 10s	260	°C	

#### **Thermal Characteristics**

Parameter	Symbol	Test Conditions	Value			Units
			Min	Тур	Max	Units
Thermal resistance, junction-to-case	$R_{\theta JC}$			0.36	0.47	°C/W



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#### Electrical Characteristics (T<sub>J</sub> = +25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Value			Linita
			Min	Тур	Max	- Units
	V <sub>F</sub>	I <sub>F</sub> = 50A, T <sub>J</sub> =25°C	-	1.5	1.7	V
Forward voltage		I <sub>F</sub> = 50A, T <sub>J</sub> =150°C	-	1.95	2.4	
		I <sub>F</sub> = 50A, T <sub>J</sub> =175°C	-	2.2	2.7	
Deveree everent	I <sub>R</sub>	V <sub>R</sub> =1200V, T <sub>J</sub> =25°C	-	52	400	μΑ
Reverse current		V <sub>R</sub> =1200V, T <sub>J</sub> =175°C	-	900		
Total capacitive charge <sup>(1)</sup>	Q <sub>C</sub>	V <sub>R</sub> =800V		240		nC
	С	$V_R$ =1V, f = 1MHz		2340		pF
Total capacitance		V <sub>R</sub> =400V, f = 1MHz		224		
		V <sub>R</sub> =800V, f = 1MHz		198		
Capacitance stored energy	E <sub>C</sub>	V <sub>R</sub> =800V		72		μ

(1)  $Q_c$  is independent on  $T_J$ ,  $di_F/dt$ , and  $I_F$  as shown in the application note USCi\_AN0011.

#### **Typical Performance Diagrams**

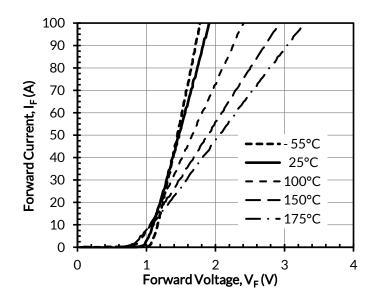


Figure 1. Typical forward characteristics

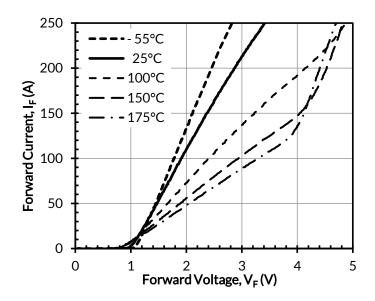


Figure 2. Typical forward characteristics in surge current



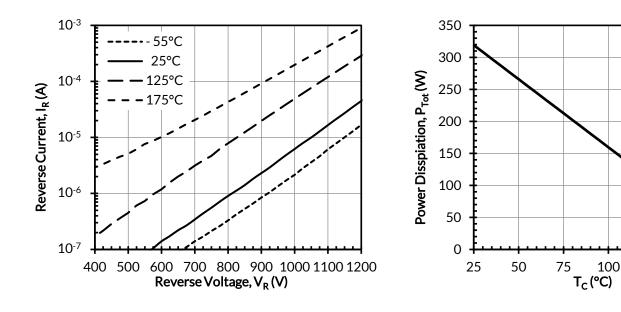


Figure 3. Typical reverse characteristics

Figure 4. Power dissipation

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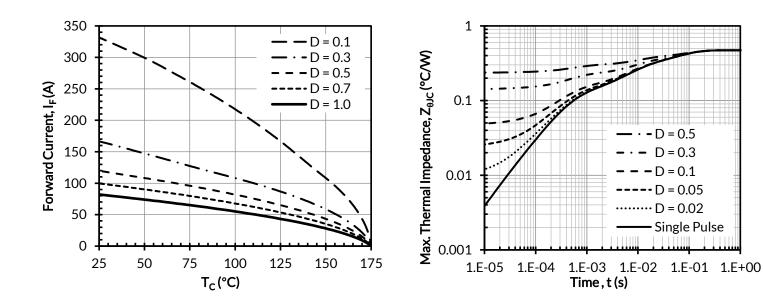


Figure 5. Diode forward current

Figure 6. Maximum transient thermal impedance





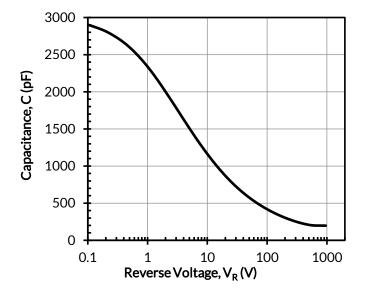


Figure 7. Capacitance vs. reverse voltage at 1MHz

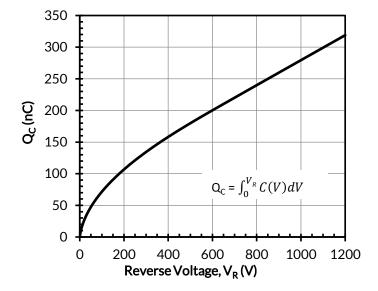


Figure 8. Typical capacitive charge vs. reverse voltage

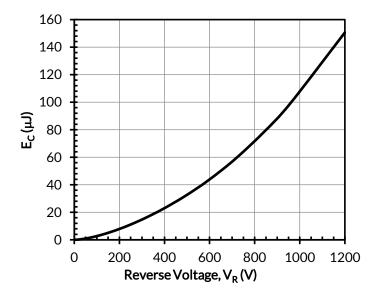


Figure 9. Typical capacitance stored energy vs. reverse voltage









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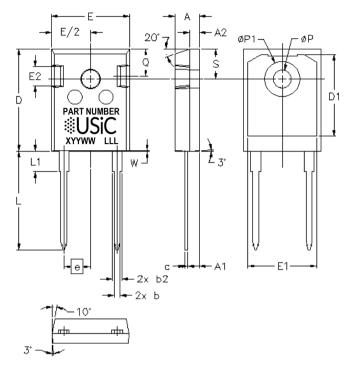
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## TO-247-2L PACKAGE OUTLINE, PART MARKING AND TUBE SPECIFICATIONS

## **PACKAGE OUTLINE**



SYM	INCHES		MILLIN	<b>IETERS</b>	
	MIN	MAX	MIN	MAX	
A	0.185	0.209	4.70	5.31	
A1	0.087	0.102	2.21	2.61	
A2	0.059	0.098	1.50	2.49	
b	0.039	0.055	0.99	1.40	
b2	0.065	0.094	1.65	2.39	
b4	0.102	0.135	2.59	3.43	
С	0.015	0.035	0.38	0.89	
D	0.819	0.845	20.80	21.46	
D1	0.515	-	13.08	-	
D2	0.02	0.053	0.51	1.35	
E	0.610	0.640	15.49	16.26	
е	0.214	4 BSC	5.44 BSC		
E1	0.530	-	13.46	-	
E2	0.135	0.157	3.43	3.99	
L	0.780	0.800	19.81	20.32	
L1	-	0.177	-	4.50	
ØР	0.140	0.144	3.56	3.66	
ØP1	0.278	0.291	7.06	7.39	
Q	0.212	0.244	5.39	6.20	
S	0.243	3 BSC	6.17	BSC	
W	-	0.006	-	0.15	



### PART MARKING

## PART NUMBER Silver Silv

PART NUMBER = REFER TO DS\_PN DECODER FOR DETAILS

X = ASSEMBLY SITE YY = YEAR WW = WORK WEEK LLL = LOT ID

### PACKING TYPE

ANTI-STATIC TUBE

**QUANTITY / TUBE : 30 UNITS** 

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